# Low Noise, DC/DC Charge Pump Regulator

## **Description**

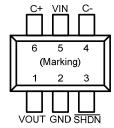
The FP6770 is a low noise DC/DC charge pump regulator that produces a regulated output voltage from 2.7V to 4.5V input voltage. Low external parts count (one flying capacitor and two small bypass capacitors at  $V_{\text{IN}}$  and  $V_{\text{OUT}}$ ) make the FP6770 ideal for small, battery-powered applications.

The FP6770 operates as a constant frequency mode switched capacitor voltage doubler to produce a regulated output and reduces both output and input ripple. The FP6770 has both short circuit protection and thermal shutdown capability.

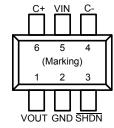
The FP6770 is available in space-saving SOT-23-6 TSOT-23-6 and TDFN-6 packages.

## **Pin Assignments**

S6 Package (SOT-23-6)



S9 Package (TSOT-23-6)



WD Package (TDFN-6) (1.6x1.6mm)

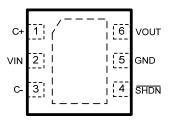


Figure 1. Pin Assignment of FP6770

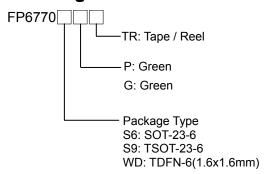
## **Features**

- Low Noise Constant Frequency Operation
- Output Current: Minimum 170mA at V<sub>IN</sub>=3.2V
- Available in SOT-23-6 
   ¬TSOT-23-6 and TDFN-6
- 2MHz Switching Frequency
- Fixed 5V ± 4% Output
- V<sub>IN</sub> Range: 2.7V to 4.5V
- No Inductors
- Low Shutdown Current: <1μA

## **Applications**

- White LEDs Backlighting
- Li-Ion Battery Backup Supplies
- Smart Card Readers
- Local 3V to 5V Conversion
- PCMCIA Local 5V Supplies

## **Ordering Information**



#### SOT-23-6 Marking

Part Number	Product Code	
FP6770S6P	C2	

#### TSOT-23-6 Marking

Part Number	Product Code	
FP6770S9P	C0	

## TDFN-6(1.6x1.6mm) Marking

Part Number	Product Code	
FP6770WDG	P.	

# **Typical Application Circuit**

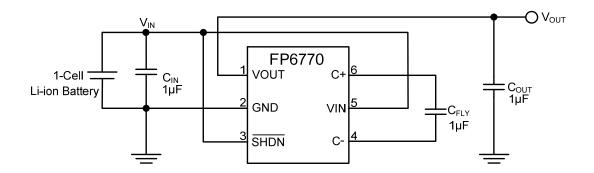


Figure 2. Typical Application Circuit of FP6770

# **Functional Pin Description**

Pin Name	Pin Function	
VOUT	Regulated output voltage. For best performance, $V_{\text{OUT}}$ should be bypassed with a $1\mu\text{F}$ (min.) low ESR capacitor as close as possible to the pin.	
GND	Ground. Should be tied to a ground plane for best performance.	
SHDN	Active low shutdown input. A low voltage on SHDN disables the FP6770. SHDN is not allowed to float.	
C-	Flying capacitor negative terminal.	
VIN	Input supply voltage. $V_{IN}$ should be bypassed with a $1\mu F$ (min.) low ESR capacitor.	
C+	Flying capacitor positive terminal.	

# **Block Diagram**

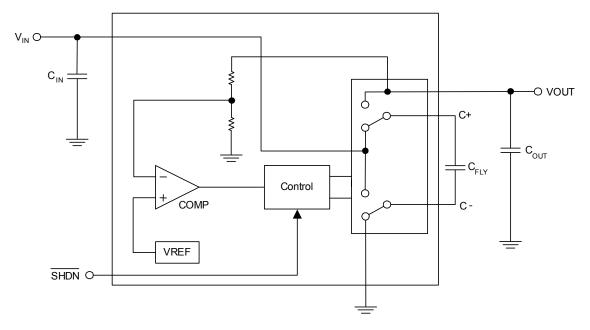


Figure 3. Block Diagram of FP6770

# **Absolute Maximum Ratings**

• V <sub>IN</sub> to GND	· 6V
• V <sub>OUT</sub> to GND	- 6V
All Other Pins to GND	- 6V
<ul> <li>Power Dissipation (P<sub>D</sub>) @ T<sub>A</sub>=25°C:</li> </ul>	
SOT-23-6 / TSOT-23-6	- 0.4W
TDFN-6 (1.6mX1.6m)(P <sub>D</sub> )	- 1.25W
Package Thermal Resistance:	
SOT-23-6 / TSOT-23-6 ( $\theta_{JA}$ )	- 250°C/W
TDFN-6(1.6mX1.6m)	80°C/W
Junction Temperature	- 150°C
Storage Temperature Range	-65°C to 150 °C
• Lead Temperature (Soldering, 10 sec.)	- 260°C
Note: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent dam	nage to the device.

# **Recommended Operating Conditions**

- Supply Voltage (V<sub>IN</sub>) ------ (2.7V to 4.5V) ±10%

## **Electrical Characteristics**

(T<sub>A</sub>=25°C, C<sub>FLY</sub>=1 $\mu$ F, C<sub>IN</sub>=1 $\mu$ F, C<sub>OUT</sub>=1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Voltage	V <sub>IN</sub>		2.7		4.5	V
Output Voltage	V <sub>OUT</sub>	2.7V≤ V <sub>IN</sub> < 4.5V, I <sub>OUT</sub> ≤ 60mA	4.8	5	5.2	٧
Output voltage	V001	3.0V≤ V <sub>IN</sub> ≤ 4.5V, I <sub>OUT</sub> ≤ 120mA	4.8	5	5.2	٧
Continuous Output Current	I <sub>OUT</sub>	V <sub>IN</sub> =3.0V, V <sub>OUT</sub> =5.0V, SHDN=V <sub>IN</sub>	100			mA
Supply Current	Icc	$ 2.7V \le V_{IN} \le 5.0V, I_{OUT} = 0, $ $ \overline{SHDN} = V_{IN} $		3	4.5	mA
Shutdown Current	SHDN	$ 2.7V \le V_{IN} \le 5.0V, I_{OUT} = 0, $ $ \overline{SHDN} = 0V $		0.01	1.0	μА
Efficiency	η	V <sub>IN</sub> =2.7V, I <sub>OUT</sub> =60mA		90		%
Switching Frequency	f <sub>OSC</sub>	Oscillator Free Running		2		MHz
(CLIDN Input Throubold	V <sub>IH</sub>	V <sub>IN</sub> =3.0V, output on	1.4			٧
/SHDN Input Threshold	VIL	V <sub>IN</sub> =3.0V, output off			0.3	٧
/CHDN Lookogo Current	I <sub>IH</sub>	SHDN=V <sub>IN</sub>	-1		1	μΑ
/SHDN Leakage Current	I <sub>IL</sub>	SHDN = 0V	-1		1	μА
V <sub>OUT</sub> Turn On Time	t <sub>ON</sub>	V <sub>IN</sub> =3V, I <sub>OUT</sub> = 1mA		200		μS
Output Short Circuit Current	I <sub>SC</sub>	V <sub>IN</sub> =3V, V <sub>OUT</sub> = 0V, SHDN =V <sub>IN</sub>		300		mA

# **Typical Performance Curves**

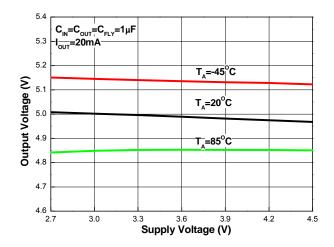


Figure 4. Output Voltage vs. Supply Voltage

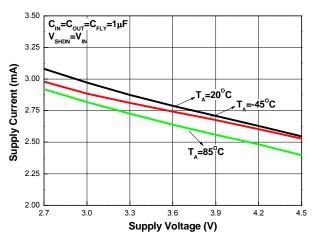


Figure 6. No Load Supply Current vs. Supply Voltage

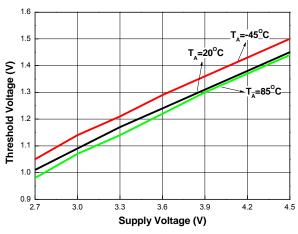


Figure 8. VSHDN Threshold Voltage vs. Supply Voltage

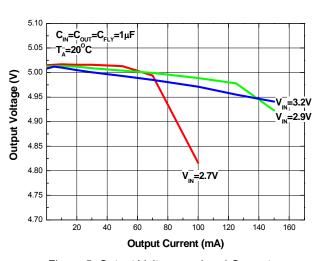


Figure 5. Output Voltage vs. Load Current

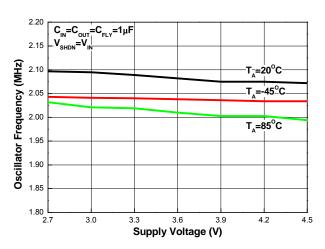


Figure 7. Oscillator Frequency vs. Supply Voltage

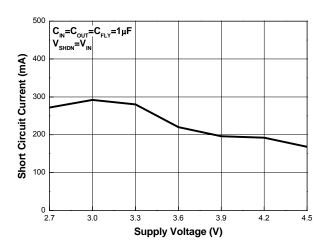


Figure 9. Short Circuit Current vs. Supply Voltage

FP6770-1.3-FEB-2010 **4** 

# **Typical Performance Curves (Continued)**

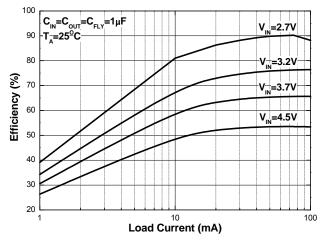


Figure 10. Efficiency vs. Load Current

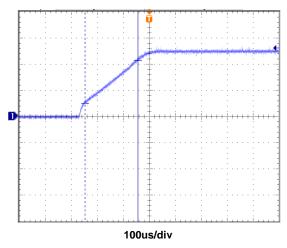


Figure 11. Output Voltage Start Up

## **Application Information**

#### Introduction

The FP6770 is a DC/DC charge pump converter that produces a regulated 5V output with an input voltage that range from 2.7V to 4.5V. It boosts  $V_{\text{IN}}$  to get a regulated output voltage using the charge pump topology. Sensing the output voltage through an internal resistor divider. When the output voltage is lower, the internal comparator will increase charge pump ability, and vice versa. When the charge pump is enabled, a two-phase non-overlapping clock activates the charge pump switches.

## **Efficiency**

Let's take advantage of conversation of charge for flying capacitor. Assume that the flying capacitor has reached its steady state.

$$I_{ON-AVE} = I_{OFF-AVE}$$
 (1)

According to the equation (1), the input current is twice the output current.

$$I_{IN} = I_{ON-AVE} + I_{OFF-AVE}$$
  
=  $2I_{OFF-AVE}$   
=  $2I_{OUT}$ 

The efficiency of charge pump is given below:

$$\eta \ = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times I_{IN}} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times 2I_{OUT}} = \frac{V_{OUT}}{2V_{IN}}$$

#### **Short Circuit/Thermal Protection**

FP6770 have a built-in short circuit current limiting and an over temperature protection. During the short circuit condition, the output current is automatically limited at approximately 300mA on  $V_{\rm IN}$ =3V. When the die temperature exceeds 160°C, the thermal protection will shut the charge pump switching operation down and the die temperature will reduce afterwards. When the die temperature drops below 135°C, the charge pump switching circuit will restart. If the fault doesn't eliminate, the above protecting operation will repeat again and again. It allows FP6770 to continuously work at short circuit condition without damaging the device.

#### Shutdown

The output is disconnected from input when /SHDN pin is tied to GND. In shutdown mode, most circuit is turned off and the input current gets extremely low. Due to high impedance, /SHDN pin can't be floated.

## **External Capacitor Selection**

Three external capacitors determine FP6770 performances, in the aspects of output ripple voltage, charge pump strength and transient. Optimum performance can be obtained by the use of ceramic capacitors with low ESR.

Because a low ESR ceramic capacitor can reduce noise and ripple, ceramic capacitor is recommended for  $C_{\text{IN}}$  and  $C_{\text{OUT}}$ . The value of  $C_{\text{OUT}}$  determines the amount of output ripple voltage. An output capacitor with larger value results in smaller ripple.

 $C_{\text{FLY}}$  determine the strength of charge pump. The larger  $C_{\text{FLY}}$  means that the larger output current and larger ripple voltage on  $V_{\text{OUT}}$  pin. However, large  $C_{\text{IN}}$  and  $C_{\text{OUT}}$  are expected when a large  $C_{\text{FLY}}$  applies.

The value of capacitors, which is used under operation condition, determines the performance of a charge pump converter. And two factors, as follows, affect the capacitance of capacitor.

There are many kinds of Ceramic capacitors materials, such as X7R, X5R, Z5U and Y5V. There have different ESR, tolerance in temperature and different cpacitance loss

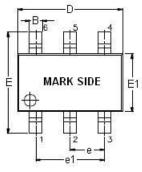
For example, a X7R or X5R type of capacitor can retain most of the capacitance at temperature from -40°C to 85°C, but a Z5U or Y5V type will lose most of the capacitance at that temperature range.

#### **Layout Considerations**

Because the high frequency and high transient current of FP6770, careful consideration of PCB layout. Minimize the distance between every component,  $C_{\text{FLY}}$  and  $C_{\text{OUT}}$  especially. It also minimizes every connection length with a maximum trace width to achieve the best performance of FP6770. Make sure each device connects to immediate ground plane.

# **Outline Information**

TSOT-23-6 Package (Unit: mm)



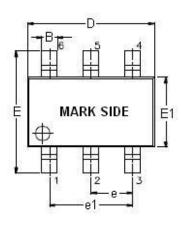


_			1 1	
H	-	$\dashv$	12	,

SYMBOLS	DIMENSION IN MILLIMETER		
UNIT	MIN	MAX	
Α	0.75	0.90	
A1	0.00	0.10	
A2	0.71	0.80	
В	0.35	0.50	
D	2.80	3.00	
Е	2.60	3.00	
E1	1.50	1.70	
е	0.90	1.00	
e1	1.80	2.00	
L	0.35	0.55	

Note: Followed From JEDEC MO-193-C.

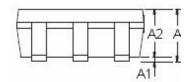
SOT-23- 6 Package (Unit: mm)





SYMBOLS	DIMENSION IN MILLIMETER		
UNIT	MIN	MAX	
Α	1.00	1.20	
A1	0.00	0.10	
A2	1.00	1.10	
В	0.35	0.50	
D	2.80	3.00	
Е	2.60	3.00	
E1	1.50	1.70	
е	0.90	1.00	
e1	1.80	2.00	
L	0.35	0.55	

Note: Followed From JEDEC MO-178-C.

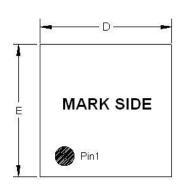


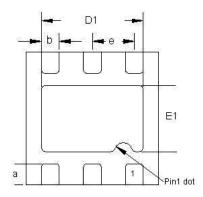
FP6770-1.3-FEB-2010 **7** 



# **Outline Information (Continued)**

TDFN- 6 1.6mmX1.6mm Package (Unit: mm)





SYMBOLS	DIMENSION IN MILLIMETER		
UNIT	MIN	MAX	
Α	0.70	0.80	
A1	0.00	0.05	
A2	0.18	0.25	
D	1.55	1.65	
E	1.55	1.65	
а	0.18	0.30	
b	0.18	0.30	
е	0.45	0.55	
D1	0.95	1.05	
E1	0.55	0.65	

Note :Followed From JEDEC MO-229-C

